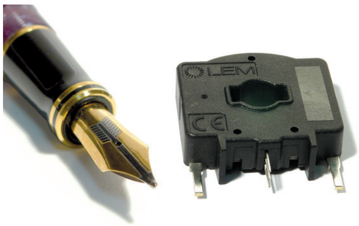
AUTOMOTIVE CURRENT TRANSDUCER OPEN LOOP TECHNOLOGY
HC6H200-S/SP2



Introduction

The HC6H family is for use on the electronic measurement of DC, AC or pulsed currents in high power and low voltage automotive applications with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit)

The HC6H family gives you the choice of having different current measuring ranges in the same housing.

Features

- Open Loop transducer using the Hall effect
- Low voltage application
- Unipolar + 5 V DC power supply
- Primary current measuring range from 200 A up to 800 A
- Maximum rms primary admissible current: defined by busbar the magnetic core or the asic to have T° < + 150 °C
- Operating temperature range: - 40 °C < T° < + 125 °C
- Output voltage: full ratio-metric (in gain and offset)
- Compact design for PCB mounting.

Special feature

- 2.54 mm secondary lead pitch.

Advantages

- Excellent accuracy
- Very good linearity
- Very low thermal offset drift
- Very low thermal gain drift
- Wide frequency bandwidth
- No insertion losses.
- Very good ratio size/current range.

Automotive applications

- Starter Generators
- Converters
- Inverters
- Drives.

Principle of HC6H Family

The open loop transducers uses a Hall effect integrated circuit. The magnetic flux density B, contributing to the rise of the Hall voltage, is generated by the primary current I_P to be measured. The current to be measured I_P is supplied by a current source i.e. battery or generator (Figure 1).
Within the linear region of the hysteresis cycle, B is proportional to:

$$B\,(I_P) = \text{constant (a)} \times I_P$$

The Hall voltage is thus expressed by:

$$V_H = (R_H/d) \times I \times \text{constant (a)} \times I_P$$

Except for I_P, all terms of this equation are constant. Therefore:

$$V_H = \text{constant (b)} \times I_P$$

The measurement signal V_H amplified to supply the user output voltage or current.

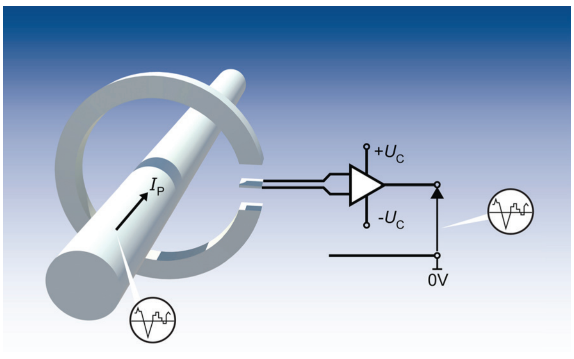


Fig. 1: Principle of the open loop transducer

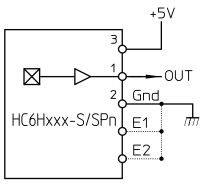
Dimensions HC6H200-S/SP2 (in mm)

Secondary connection

Terminals	Designations
3	Supply voltage + 5 V DC
1	V_{out}
2	Ground
E1, E2	Ground (*)

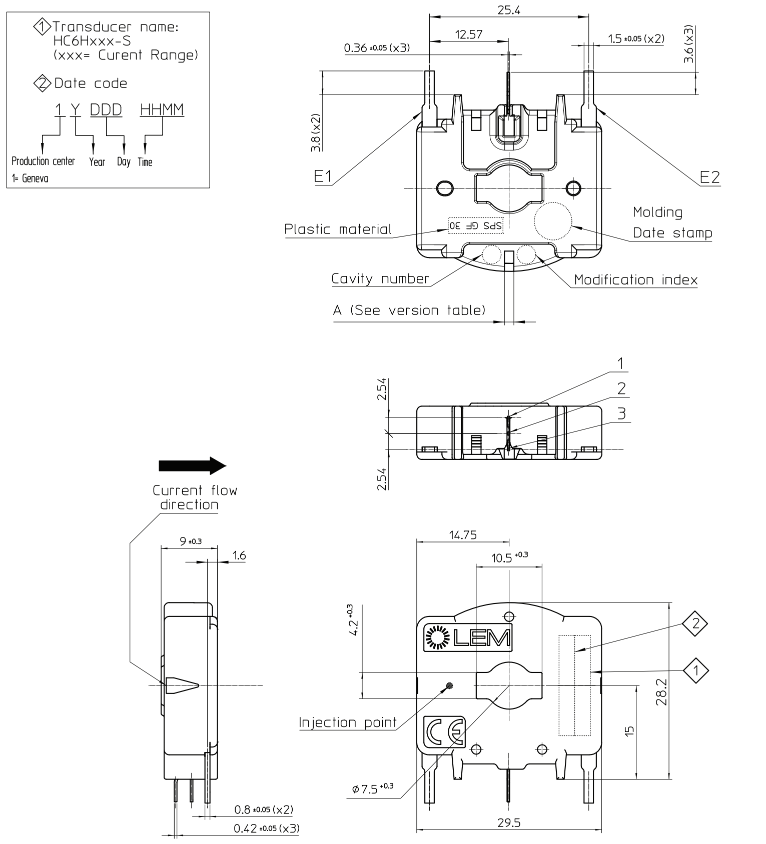
* Only 1 of these 2 pins could be connected

Connection



xxx = Current Range

VERSION TABLE of CURRENT RANGE	
A	C RRENT RANGE
1.5 mm	I_P <= 600 A
3 mm	I_P > 600 A



Drawing for information only

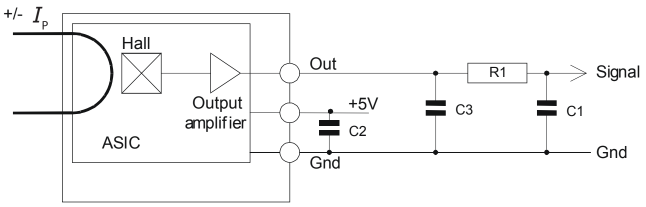
Mechanical characteristics

- Plastic case — SPS GF 30
- Magnetic core — FeSi alloy
- Terminal raw material — Copper alloy
- Electrical terminal coating — Tin plated (lead free)
- Mass — 23 g

Remarks

- $I_P = \left(\frac{5}{U_C} \cdot V_{out} - V_O\right) \cdot \frac{1}{G}$ with G in (V/A)
- $V_{out} > V_o$ when I_P flows in the positive direction (see arrow on drawing).

Electronic schematic



Power supply decoupling capacitor: C2 = 47 nF
EMC protection capacitor C3 = 4.7 nF

Optional:

High frequency signal noise filter:

R1 > 100 Ω

C1 = defined according to the system frequency bandwidth

HC6H200-S/SP2

Absolute ratings (not operating)

Parameter	Symbol	Unit	Specification			Conditions
			Min	Typical	Max	
Maximum peak primary current (not operating)	I_P	A				Defined by busbar to have ≤ 150 °C
Primary current DC or current RMS	I_{PN}	A				Defined by busbar to have ≤ 150 °C
Maximum supply voltage (not operating)	U_C	V		7		
Secondary maximum admissible power	P_S	mV		150		
Ambient operating temperature	T_A	°C	- 40		125	
Ambient storage temperature	T_S	°C	- 40		125	
Electrostatic discharge voltage	U_{ESD}	V			2000	JESD22-A 114-B
Maximum admissible vibration (random)	γ	m·s⁻²		[3]		See note [3]
RMS voltage for AC insulation test, 50 Hz, 1 min	U_d	V			2000	IEC 60664 part 1
Maximun supply voltage	U_C	V			0.5	1 min @T_A = 25 °C

Operating characteristics in nominal range (I_{PN})

Parameter	Symbol	Unit	Specification			Conditions
			Min	Typical	Max	
Electrical Data						
Supply voltage [1]	U_C	V	4.75	5	5.25	@ - 40 °C < T° < 125 °C
Current consumption	I_C	mA		15	20	@ - 40 °C < T° < 125 °C, @ 4.75 V < U_C < 5.25 V
Primary current, measuring current	I_{PM}	A	- 200		200	@ - 40 °C < T° < 125 °C
Analog output voltage	V_{out}	V	$V_{out} = (U_C/5) \cdot (V_o + G \cdot I_P)$			@ - 40 °C < T° < 125 °C
Sensitivity	G	V/A	0.0098	0.010	0.0102	@T_A = 25 °C
Offset voltage	V_O	V	2.482	2.5	2.518	@ U_C = 5 V, @T_A = 25 °C I_P = 0 A
Load resistance	R_L	KΩ	10			
Capacitive loading	R_{out}	Ω			10	
Performance Data						
Sensitivity error	ε_G	%	- 2	± 0.7	2	@T_A = 25 °C, U_C = 500 V, Gth = 0.010
Electrical offset	I_{OE}	A	- 1.3	± 0.5	1.3	@T_A = 25 °C, U_C = 5 V
	V_{OE}	mV	- 13	± 5	13	
Magnetic offset	I_{OM}	A	- 2.4	± 1.5	2.4	@ after excursion to ± I_P, T_A = 25 °C
	V_{OM}	mV	- 24	± 15	24	
Average temperature coefficient of	TCI_{OEAV}	mA/°C	- 14	± 8	14	@ - 40 °C < T° < 125 °C, U_C = 5 V
	TCV_{OEAV}	mV/°C	- 0.14	± 0.08	0.14	
Average temperature coefficient of G	TCG_{AV}	%/°C	- 0.04	± 0.02	0.04	@ - 40 °C < T° < 125 °C, U_C = 5 V
Linearity error	ε_L	% I_P	- 1	± 0.5	1	@ I_P, U_C = 5 V, @T_A = 25 °C
Response time	t_r	µs		8	15	@ di/dt = 50 A/µs, I_T = 40 A rms
Frequency bandwidth [2]	BW	kHz	20			@ 3 dB, I_T = 40 A rms
Output voltage noise peak-peak	$V_{no\ p\text{-}p}$	mV		23	28	@T_A = 25 °C, 0 Hz < f < 1 MHz
Output RMSvoltage noise	V_{no}	mV		2	3.5	@T_A = 25 °C, 0 Hz < f < 1 MHz

Notes:

[1] The output voltage V_{out} is fully ratiometric and depends on the supply voltage U_C. The U_C value must be measured relative to the following formula:

$$I_P = \left(\frac{5}{U_C} \cdot V_{out} - V_O\right) \cdot \frac{1}{G} \quad \text{with } G \text{ in (V/A)}$$

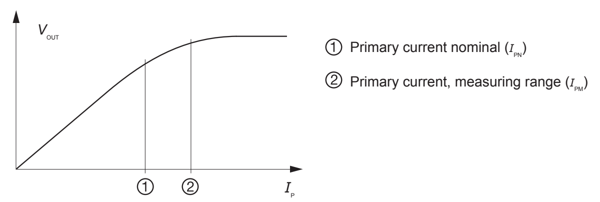
[2] Small signal only to avoid excessives heatings of the busbar, the magnetic core and the ASIC (< 150 °C)

[3] Depending on the customer application's set up

[4] Transducer not protected against reverse polarity.

PERFORMANCES PARAMETERS DEFINITIONS

Output noise voltage:



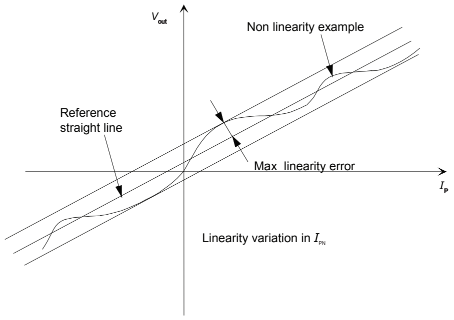
The output voltage noise is the result of the noise floor of the Hall elements and the linear amplifier.

Magnetic offset:

The magnetic offset is the consequence of an over-current on the primary side. It's defined after an excursion of I_{PN}.

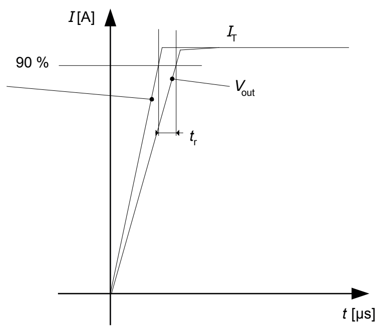
Linearity:

The maximum positive or negative discrepancy with a reference straight line $V_{out} = f\,(I_P)$.
Unit: linearity (%) expressed with full scale of I_{PN}.



Response time (delay time) t_r:

The time between the primary current signal (I_{PN}) and the output signal reach at 90 % of its final value.



Typical:
Theorical value or usual accuracy recorded during the production.

Sensitivity:
The Transducer's sensitivity G is the slope of the straight line $V_{out} = f\,(I_P)$, it must establish the relation:
$V_{out}\,(I_P) = U_C/5\,(G \cdot I_P + V_o)$

Offset with temperature:

The error of the offset in the operating temperature is the variation of the offset in the temperature considered with the initial offset at 25 °C.
The offset variation I_{OT} is a maximum variation the offset in the temperature range:
$I_{OT} = I_{OE}\,\text{max} - I_{OE}\,\text{min}$
The Offset drift TCI_{OEAV} is the I_{OT} value divided by the temperature range.

Sensitivity with temperature:

The error of the sensitivity in the operating temperature is the relative variation of sensitivity with the temperature considered with the initial offset at 25 °C.
The sensitivity variation G_T is the maximum variation (in ppm or %) of the sensitivity in the temperature range:
G_T = (Sensitivity max - Sensitivity min) / Sensitivity at 25 °C.
The sensitivity drift TCG_{AV} is the G_T value divided by the temperature range. Deeper and detailed info available is our LEM technical sales offices (www.lem.com).

Offset voltage @ I_P = 0 A:

The offset voltage is the output voltage when the primary current is null. The ideal value of V_O is $U_C/2$ at U_C = 5 V. So, the difference of $V_O - U_C/2$ is called the total offset voltage error. This offset error can be attributed to the electrical offset (due to the resolution of the ASIC quiescent voltage trimming), the magnetic offset, the thermal drift and the thermal hysteresis. Deeper and detailed info available is our LEM technical sales offices (www.lem.com).

Environmental test specifications:

Name	Standard	Conditions
Thermal shocks	IEC 60068 Part 2-14	T° - 40 °C to 125 °C /1000 cycles not connected
Low T° operating endurance	Mitsubishi ES-X 82113_E	T° - 40 °C / 120 h supply voltage = 5 V
High T° operating endurance	Mitsubishi ES-X 82113_E	T° 125 °C / 1464 h supply voltage = 5 V
Temperature humidity bias	IEC 60068 Part 2-3	T° 85 °C / 85 % RH/ 1000h
Mechanical Tests		
Random vibration	IEC 60068 Part 2-64	96 h, 1g, 20 Hz to 500
Packaging drop test	JIS C 60068-2-31:1995	1 box, 4 bottom corners, 10 cm high, topple test
EMC Test		
Electrostatic discharge	JESD22-A114-B	Applied voltage = ± 2 kV pin to pin number of discharge = 1
Rms voltage for AC isolation test	IEC 60664 Part 1	2 kV, 50 Hz, 1 min
Bulk current injected-radiated immunity	ISO 11452 Part 4	